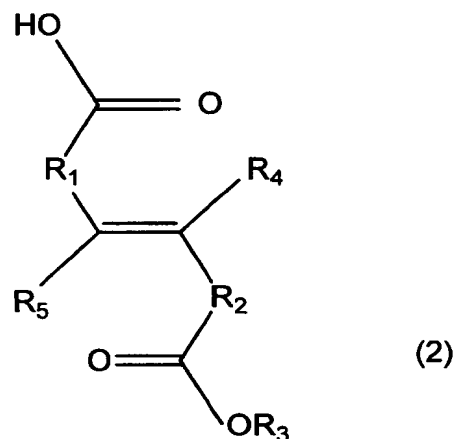
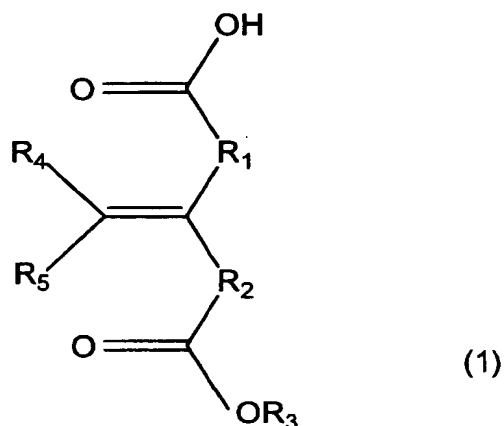


## ABSTRACT

A negative resist composition includes a polymer having any one of dicarboxylate monoester compounds represented by the following general formulae (1) and (2) as a monomer component:



wherein,  $R_1$  and  $R_2$  represent alkyl chains having 0 to 5 carbon atoms,  $R_3$  represents a substituent having at least two or more alicyclic structures, and  $R_4$  and  $R_5$  represent hydrogen atoms or alkyl groups having 1 to 8 carbon atoms. A method for forming a resist pattern uses the above negative resist composition. By containing the polymer, a resistance to dry etching and a resistance to electron beam from a scanning electron microscope (SEM) are enhanced as well as a solubility in an alkali developing solution is maintained.